TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOSVI)

TPC6113

Lithium Ion Battery Applications

Power Management Switch Applications

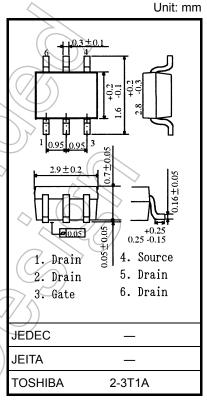
- Small footprint due to small and thin package
- Low drain-source ON-resistance: R_{DS} (ON) = 38 m Ω (typ.)

$$(V_{GS} = -4.5V)$$

- Low leakage current: $IDSS = -10 \mu A (max) (VDS = -20 V)$
- Enhancement mode: $V_{th} = -0.5$ to -1.2 V $(V_{DS} = -10$ V, $I_{D} = -0.2$ mA)

Absolute Maximum Ratings (Ta = 25°C)

| Character | istics | Symbol | Rating | Unit |
|---|-----------------------------|--------------------|-------------|------|
| Drain-source voltage | | V_{DSS} | -20 | V |
| Drain-gate voltage (Re | $GS = 20 \text{ k}\Omega$) | V_{DGR} | -20 | À |
| Gate-source voltage | | V _{GSS} | <u>±</u> 12 | > v |
| Drain current | DC (Note 1) | I _D | _5 | А |
| Drain current | Pulse (Note 1) | I _{DP} | -20 | ^ |
| Drain power dissipation | on (t = 5 s) (Note 2a) | PD | 2.2 | (w |
| Drain power dissipation (t = 5 s) (Note 2b) | | PD | 0.7 | W |
| Single pulse avalanch | e energy (Note 3) | EAS | 1.6 | mJ |
| Avalanche current | | (I _{AR}) | -2.5 | JA |
| Channel temperature | (| 7) (ch | 150 | °C |
| Storage temperature | range | T _{stg} | -55 to 150 | →°C |



Weight: 0.011 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated/failure rate, etc).

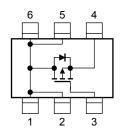
Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|--|------------------------|-------|------|
| Thermal resistance, channel to ambient ($t = 5 \text{ s}$) (Note 2a) | R _{th (ch-a)} | 56.8 | °C/W |
| Thermal resistance, channel to ambient $(t = 5 \text{ s})$ (Note 2b) | R _{th (ch-a)} | 178.5 | °C/W |

Note: (Note 1), (Note 2), (Note 3): See other pages.

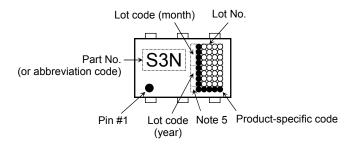
This transistor is an electrostatic-sensitive device. Please handle with caution.

Circuit Configuration



Start of commercial production 2009-11

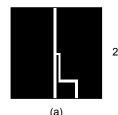
Marking (Note 4)



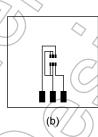
Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a) (t = 5 s)

(b) Device mounted on a glass-epoxy board (b) (t = 5 s)



FR-4 $25.4\times25.4\times0.8$ (Unit: mm)



25.4 × 25.4 × 0.8 (Unit: mm)

Note 3: $V_{DD} = -16 \text{ V}$, $T_{ch} = 25^{\circ}\text{C}$ (initial), L = 0.2 mH, $R_G = 25 \Omega$, $I_{AR} = -2.5 \text{ A}$

Note 4: • on lower left of the marking indicates Pin 1.

Note 5: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[F0]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8

June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.





Electrical Characteristics (Ta = 25°C)

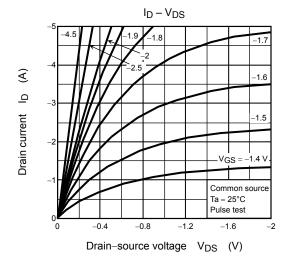
| Ch | aracteristics | Symbol | Test Condition | Min | Тур. | Max | Unit | |
|--|---------------|----------------------|---|---------------|--------|----------|------|--|
| Gate leakage cui | rrent | I _{GSS} | $V_{GS} = \pm 12 \text{ V}, V_{DS} = 0 \text{ V}$ | _ | _ | ±100 | nA | |
| Drain cut-off curr | ent | I _{DSS} | V _{DS} = -20 V, V _{GS} = 0 V | _ | _ | -10 | μΑ | |
| Drain-source breakdown voltage | | V (BR) DSS | $I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$ | -20 | _ | _ | V | |
| | | V (BR) DSX | $I_D = -10 \text{ mA}, V_{GS} = 8 \text{ V (Note 6)}$ | -12 | _ | _ | | |
| Gate threshold v | oltage | V _{th} | $V_{DS} = -10 \text{ V}, I_D = -0.2 \text{ mA}$ | -0.5 |) /_ | -1.2 | V | |
| Drain-source ON-resistance | | R _{DS (ON)} | $V_{GS} = -2.5 \text{ V}, I_D = -2.5 \text{ A}$ |) | 56 | 85 | mΩ | |
| | | R _{DS} (ON) | $V_{GS} = -4.5 \text{ V}, I_D = -2.5 \text{ A}$ | \rightarrow | 38 | 55 | | |
| Input capacitance | | C _{iss} | | | 690 | _ | | |
| Reverse transfer capacitance | | C _{rss} | $V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$ | _ | 93 | _ | pF | |
| Output capacitance | | Coss | | _ | 117 | _ | | |
| | Rise time | t _r | Vcs 0 V 7 D = 2.5 A | - (| 6 | <u> </u> | - | |
| Considerable and disease | Turn-on time | t _{on} | VGS 0 V D = 2.5 A O VOUT | _((| 13 |) — | | |
| Switching time | Fall time | t _f | 4.7.4. W O ST | 7 | _ 25 _ | ns | | |
| | Turn-off time | t _{off} | $V_{DD} \approx -10 \text{ V}$ Duty $\leq 1\%$, $t_W = 10 \mu\text{s}$ | | 81 | _ | | |
| Total gate charge (gate-source plus | | Qg | V _{DD} ≈ -16 V, V _G s = -5 V, |) _ | 10 | | | |
| Gate-source charge 1 | | Q _{gs1} | ID = -5 A | _ | 1.3 | _ | nC | |
| Gate-drain ("miller") charge | | Q _{gd} | | _ | 2.8 | _ | | |

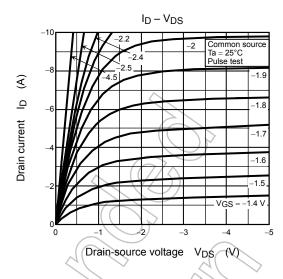
Source-Drain Ratings and Characteristics (Ta = 25°C)

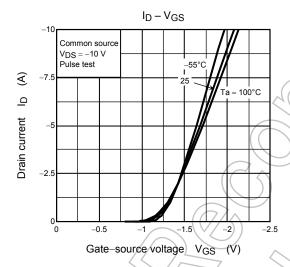
| Charact | teristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|-----------------------|----------------|------------------|---|-----|------|-----|------|
| Drain reverse current | Pulse (Note 1) | IDRP | $\langle \langle \rangle \rangle$ | _ | _ | -20 | Α |
| Forward voltage | (diode) | V _{DSF} | $I_{DR} = -5 \text{ A}, V_{GS} = 0 \text{ V}$ | _ | _ | 1.2 | V |

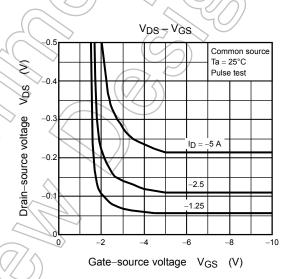
Note 6: VDSX mode (the application of a plus voltage between gate and source) may cause decrease in maximum rating of drain-source voltage.

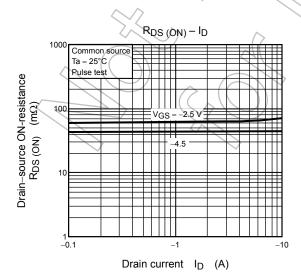
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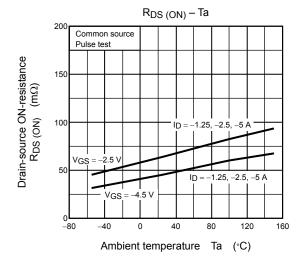


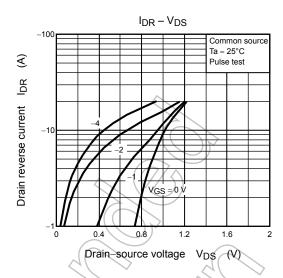


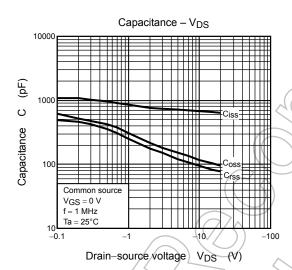


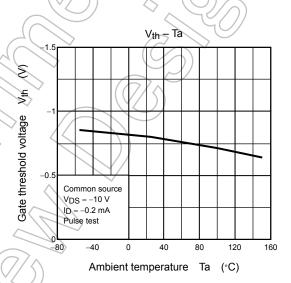
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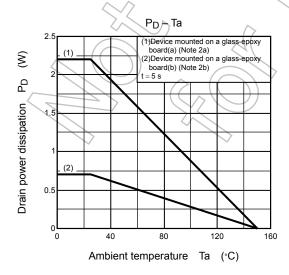
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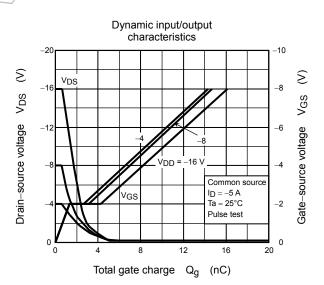


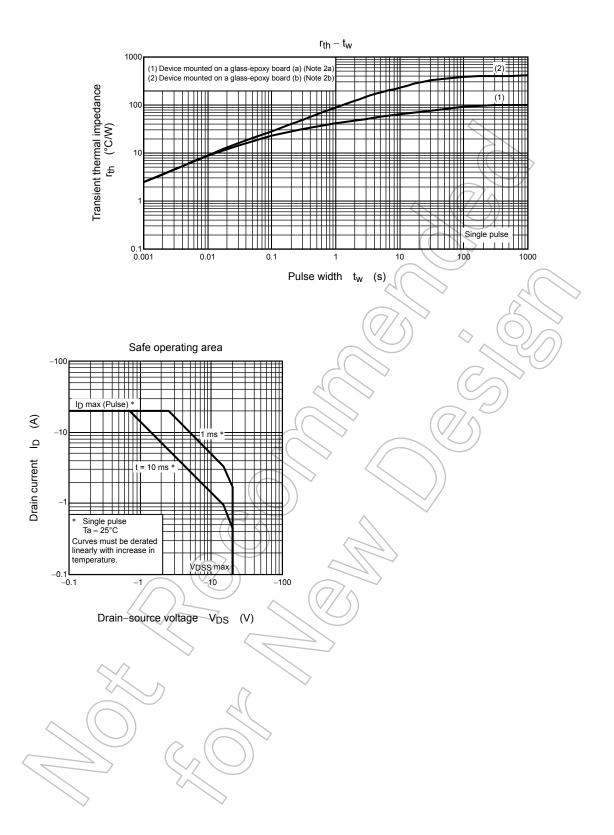












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